

SBL3030CT - SBL3040CT

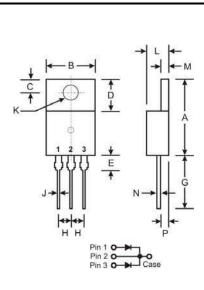
30A SCHOTTKY BARRIER RECTIFIER

Features

- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters,
- Free Wheeling, and Polarity Protection Applications
 Lead Free Finish, RoHS Compliant (Note 3)

Mechanical Data

- Case: TO-220AB
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020C
- Terminals: Finish Tin. Solderable per MIL-STD-202, Method 208 @3
- Polarity: As Marked on Body
- Marking: Type Number
- Ordering Information: See Page 3
- Weight: 2.24 grams (approximate)



TO-220AB				
Dim	Min	Max		
Α	14.48	15.75		
В	10.00	10.40		
С	2.54	3.43		
D	5.90	6.40		
Е	2.80	3.93		
G	12.70	14.27		
н	2.40	2.70		
J	0.69	0.93		
к	3.54	3.78		
L	4.07	4.82		
М	1.15	1.39		
Ν	0.30	0.50		
Р	2.04	2.79		
All Dimensions in mm				

Maximum Ratings and Electrical Characteristics @T_A = 25[°]C unless otherwise specified

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

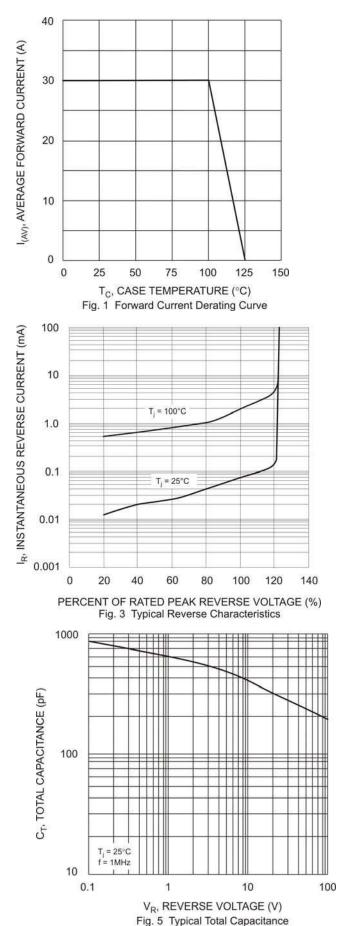
Characteristic	Symbol	SBL 3030CT	SBL 3040CT	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	30	40	V
RMS Reverse Voltage	V _{R(RMS)}	21	28	V
Average Rectified Output Current (Note 1) $@ T_c = 100^{\circ}C$	Ι _ο	30		А
Non-Repetitive Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load	I _{FSM}	250		А
Forward Voltage Drop $@$ I _F = 15A, T _C = 25°C	V _{FM}	0.55		V
Peak Reverse Current $@T_{C} = 25^{\circ}C$ at Rated DC Blocking Voltage $@T_{C} = 100^{\circ}C$	I _{RM}	1.0 75		mA
Typical Total Capacitance (Note 2)	C _T	450		pF
Typical Thermal Resistance Junction to Case (Note 1)	R _{eJC}	1.5		°C/W
Operating Temperature Range	Tj	-55 to +125		°C
Storage Temperature Range	T _{STG}	-55 to +150		°C
Critical Rate of Rise Reverse Voltage	dv/dt	10,000		V/µs

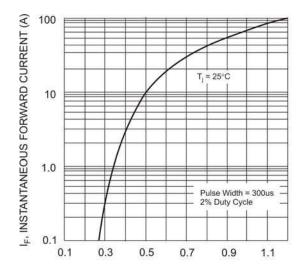
Notes: 1. Thermal resistance junction to case mounted on heatsink.

2. Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

3. RoHS revision 13.2.2003. Glass and high temperature solder exemptions applied, see EU Directive Annex Notes 5 and 7.







V_F, INSTANTANEOUS FORWARD VOLTAGE (V) Fig. 2 Typical Forward Characteristics

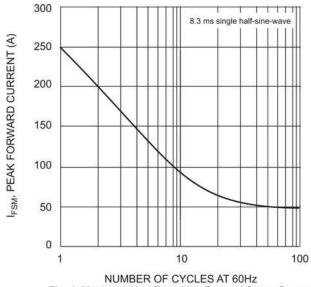


Fig. 4 Maximum Non-Repetitive Forward Surge Current



Ordering Information (Note 4)

Device	Packaging	Shipping
SBL3030CT	TO-220AB	50/Tube
SBL3040CT	TO-220AB	50/Tube

Notes: 4. For Packaging Details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

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